NSN 5961-01-015-2177

Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-015-2177 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Overall Height:** 0.170 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, base open all semiconductor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No